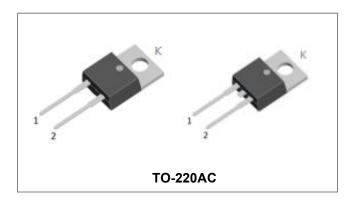


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## SDUR2040 ULTRAFAST RECTIFIER



## **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: Tin Lead-free plated
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Maximum Ratings(at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	400	V
Average Rectified Forward Current in DC	I <sub>F (AV)</sub>	Tc=114°C	20	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@20A, Pulse, T <sub>J</sub> = 25°C	0.99	1.51	V
	V <sub>F2</sub>	@20A, Pulse, T <sub>J</sub> =125°C	1.88	1.40	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ $T_J = 25^{\circ}C$	0.4	15	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125$ °C	283	500	uA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	30	45	ns

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

<sup>•</sup> China - Germany - Korea - Singapore - United States •

http://www.smc-diodes.comsales@ smc-diodes.com



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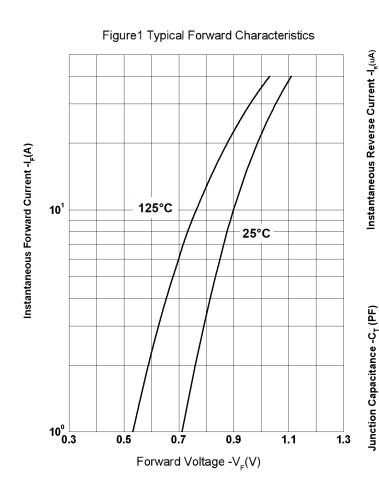


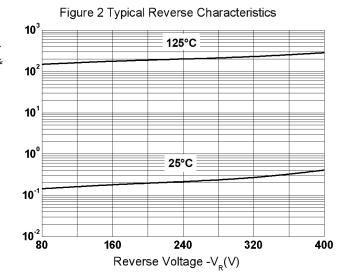


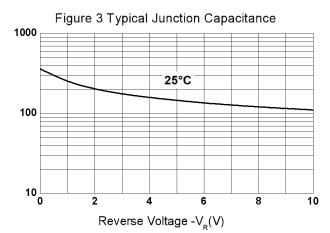
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	1.2	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

# **Ratings and Characteristics Curves**







<sup>•</sup> China - Germany - Korea - Singapore - United States •

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •

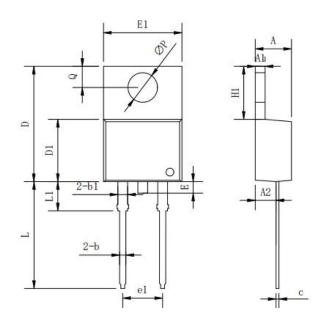


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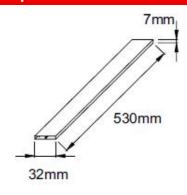


## **Mechanical Dimensions TO-220AC**

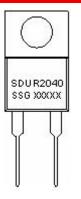


Symbol	Dimensions in millimeters			
	Min. Typical		Max.	
Α	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	-	-	1.78	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

# **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 20 = Forward Current (20A) 40 = Reverse Voltage(400V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping	
SDUR2040	TO-220AC (Pb-Free)	50 pcs/ tube	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

#### **SDUR2040**



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